

SL52C THRU SL510C

Reverse Voltage - 20 to 100 Volts Forward Current - 5.0 Ampere

SURFACE MOUNT SCHOTTKY BARRIER DIODES

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction,majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief,ideal for automated placement
- ◆ High forward surge current capability
- ♦ High temperature soldering guaranteed: 260°C/10 seconds at terminals

0.126 (3.20) 0.114 (2.90) 0.280(7.11) 0.280(7.11) 0.280(6.60) 0.013(2.62) 0.079(2.08) 0.080(0.152) 0.080(0.203)MAX. 0.320(8.13) 0.320(8.75)

Dimensions in inches and (millimeters)

Mechanical Data

Case: JEDEC DO-214AB/SMC Molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Polarity symbol marking on body

Mounting Position: Any

Weight: 0.007ounce, 0.25 grams

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter		SL52C	SL53C	SL54C	SL55C	SL56C	SL58C	SL510C	UNITS
Marking Code		MDD SL52C	MDD SL53C	MDD SL54C	MDD SL55C	MDD SL56C	MDD SL58C	MDD SL510C	
Maximum repetitive peak reverse voltage	VRRM	20	30	40	50	60	80	100	V
Maximum RMS voltage	VRMS	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	VDC	20	30	40	50	60	80	100	V
Maximum average forward rectified current at TL=90°C	l(AV)	5.0						А	
Peak forward surge current									
8.3ms single half sine-wave					120				Α
superimposed onrated load (JEDEC Method)									
Maximum instantaneous forward voltage at 5.0A	VF	0.45 0.50 0.70				70	V		
Maximum DC reverse current Ta=25°C				0.5			1	.2	A
at rated DCblocking voltage Ta=125℃		20.0						mA	
Typical junction capacitance (NOTE 1)		200						pF	
Typical thermal resistance (NOTE 2)		55.0						°C/W	
Operating junction temperature range	TJ	- 5 5 t o + 1 2 5 -55 to +150					+150	$^{\circ}$	
Operating storage temperature range	Тѕтс	-55 to +150						$^{\circ}\mathbb{C}$	

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

DN:T20519A0

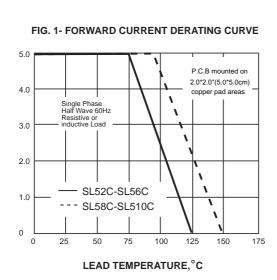




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Ratings And Characteristic Curves







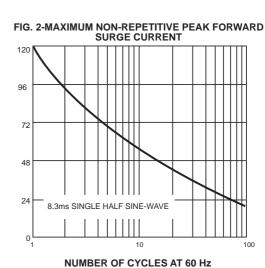


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

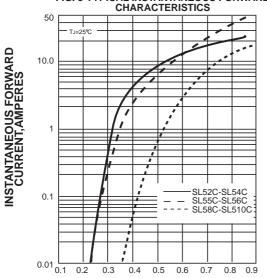
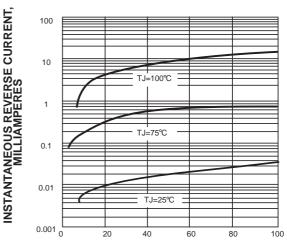
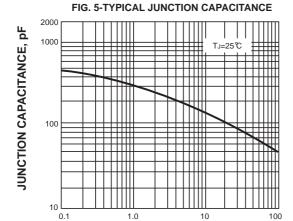


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

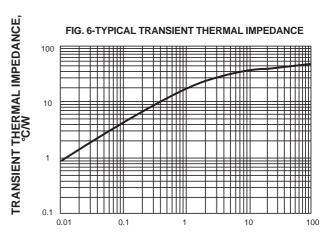


INSTANTANEOUS FORWARD VOLEAGE, VOLTS



REVERSE VOLTAGE, VOLTS

PERCENT OF PEAK REVERSE VOLTAGE,%



t,PULSE DURATION,sec.

The curve above is for reference only.

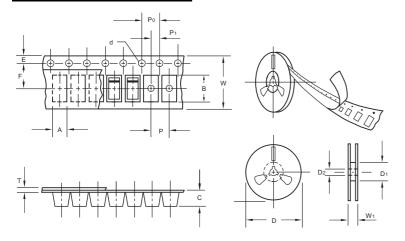
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Packing information



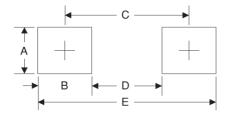
			unit:mm	
ltem	Symbol	Tolerance	SMC	
Carrier width	Α	0.1	6.15	
Carrier length	В	0.1	8.41	
Carrier depth	С	0.1	2.42	
Sprocket hole	d	0.05	1.50	
13" Reel outside diameter	D	2.0	330.00	
13" Reel inner diameter	D1	min	50.00	
Feed hole diameter	D2	0.5	13.00	
Sprocket hole position	Е	0.1	1.75	
Punch hole position	F	0.1	7.50	
Punch hole pitch	Р	0.1	8.00	
Sprocket hole pitch	P ₀	0.1	4.00	
Embossment center	P1	0.1	2.00	
Overall tape thickness	Т	0.1	0.25	
Tape width	W	0.3	16.00	
Reel width	W1	1.0	16.50	

Note:Devices are packed in accor dance with EIA standar RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (mm)	BOX (pcs)	INNER BOX (mm)	REEL DIA, (mm)	CARTON SIZE (mm)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMC	13"	3,000	4.0	6000	190*190*41	330	365*365*340	42000	14.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
Α	4.3	0.170
В	4.1	0.160
С	7.9	0.311
D	3.8	0.150
E	12	0.472

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